Vishay General Semiconductor

## **Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.58$  V at  $I_F = 2.5$  A



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PRIMARY CHARACTERISTICS					
Package	TO-220AB				
I <sub>F(AV)</sub>	2 x 5.0 A				
V <sub>RRM</sub>	200 V				
I <sub>FSM</sub>	80 A				
V <sub>F</sub> at I <sub>F</sub> = 5.0 A	0.65 V				
T <sub>J</sub> max.	150 °C				
Diode variations	Common cathode				

### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

### MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VT10200C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	200	V	
Maximum average forward rectified current (fig. 1)	per device		10.0	^	
	per diode	IF(AV)	5.0	— A	
Peak forward surge current 8.3 ms single half sine-way on rated load per diode	I <sub>FSM</sub>	80	A		
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		TJ, T <sub>STG</sub>	- 40 to + 150	°C	

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	l <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	V <sub>BR</sub>	200 (minimum)	-	V		
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	- T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.81	-	V		
	I <sub>F</sub> = 5.0 A			1.10	1.60			
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.58	-			
	$I_{F} = 5.0 \text{ A}$			0.65	0.73			
Reverse current per diode	V <sub>R</sub> = 180 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> (2)	1.7	-	μA		
		T <sub>A</sub> = 125 °C		1.8	-	mA		
	V <sub>R</sub> = 200 V	T <sub>A</sub> = 25 °C		-	150	μA		
		T <sub>A</sub> = 125 °C		2.5	10	mA		

Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

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RoHS COMPLIANT HALOGEN



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<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VT10200C	UNIT	
Typical thermal resistance	per diode	$R_{ ext{ heta}JC}$	3.5	°C/W	
Typical mermai resistance	per device		2.5	0/10	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	VT10200C-M3/4W	1.88	4W	50/tube	Tube	

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

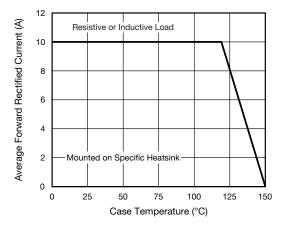


Fig. 1 - Maximum Forward Current Derating Curve

D = 0.8

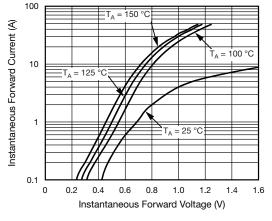


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

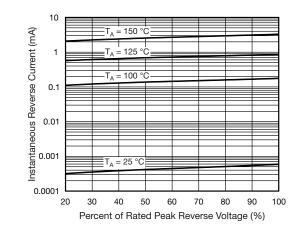


Fig. 4 - Typical Reverse Characteristics Per Diode

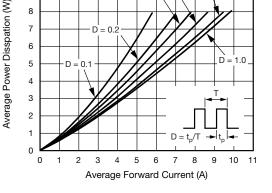


Fig. 2 - Forward Power Loss Characteristics Per Device

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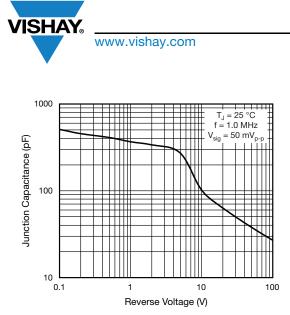


Fig. 5 - Typical Junction Capacitance Per Diode

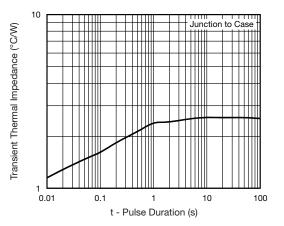
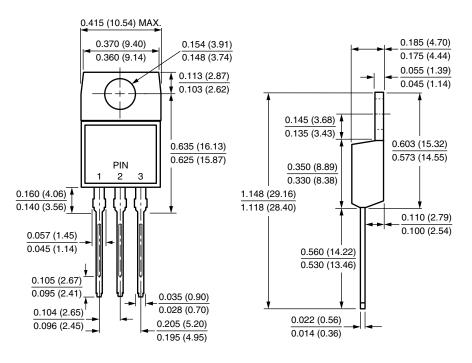


Fig. 6 - Typical Transient Thermal Impedance Per Device

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



**TO-220AB** 



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